

BC857B,235 Datasheet



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DiGi Electronics Part Number BC857B,235-DG

Manufacturer Nexperia USA Inc.

Manufacturer Product Number BC857B,235

Description TRANS PNP 45V 0.1A TO236AB

Detailed Description Bipolar (BJT) Transistor PNP 45 V 100 mA 100MHz 2

50 mW Surface Mount TO-236AB



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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
BC857B,235	Nexperia USA Inc.
Series:	Product Status:
	Active
Transistor Type:	Current - Collector (Ic) (Max):
PNP	100 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
45 V	650mV @ 5mA, 100mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
15nA (ICBO)	220 @ 2mA, 5V
Power - Max:	Frequency - Transition:
250 mW	100MHz
Operating Temperature:	Grade:
150°C (TJ)	Automotive
Qualification:	Mounting Type:
AEC-Q101	Surface Mount
Package / Case:	Supplier Device Package:
TO-236-3, SC-59, SOT-23-3	TO-236AB
Base Product Number:	
BC857	

Environmental & Export classification

8541.21.0075

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



65 V, 100 mA PNP general-purpose transistors

Rev. 9 — 1 July 2022

Product data sheet

1. General description

PNP general-purpose transistors in a small SOT23 (TO-236AB), Surface-Mounted Device (SMD) plastic package.

Table 1. Product overview

Type number	Package		NPN complement
	Nexperia	JEDEC	
BC856	SOT23	TO-236AB	BC846
BC856A			BC846A
BC856B			BC846B
BC857			BC847
BC857A			BC847A
BC857B			BC847B
BC857C			BC847C
BC858B	1		BC848B

2. Features and benefits

Low current (max. 100 mA)

Low voltage (max. 65 V)

3. Applications

· General-purpose switching and amplification



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4. Quick reference data

Table 2. Quick reference data

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base		'	•	
	BC856; BC856A; BC856B		-	-	-65	V
	BC857; BC857A; BC857B; BC857C		-	-	-45	V
	BC858B		-	-	-30	V
I _C	collector current		-	-	-100	mA
I _{CM}	peak collector current		-	-	-200	mA
h _{FE}	DC current gain	DC current gain				
	BC856		125	-	475	
	BC857		125	-	800	
	BC856A; BC857A	$V_{CE} = 5 \text{ V}; I_{C} = 2 \text{ mA}$	125	-	250	
	BC856B; BC857B; BC858B		220	-	475	
	BC857C		420	-	800	

5. Pinning information

Table 3. Pinning information

Table of Finning Information						
Pin	Symbol	Descrition	Simlified outline	Graphic symbol		
1	В	base	3	С		
2	Е	emitter		B_		
3	С	collector]	J 1		
				E sym132		
			1 2	Sy111132		

6. Ordering information

Table 4. Ordering information

Type number	Package		
	Name	Description	Version
BC856	TO-236AB	plastic surface-mounted package; 3 leads	SOT23
BC856A			
BC856B			
BC857			
BC857A			
BC857B			
BC857C			
BC858B			

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7. Marking

Table 5. Marking codes

Type number		Marking code
BC856	[1]	3D%
BC856A	[1]	3A%
BC856B	[1]	3B%
BC857	[1]	3H%
BC857A	[1]	3E%
BC857B	[1]	3F%
BC857C	[1]	3G%
BC858B	[1]	3K%

^{[1] % =} placeholder for manufacturing site code

8. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter				
	BC856; BC856A; BC856B			-	-80	V
	BC857; BC857A; BC857B; BC857C			-	-50	V
	BC858B			-	-30	V
V_{CEO}	collector-emitter voltage	open base				
	BC856; BC856A; BC856B			-	-65	V
	BC857; BC857A; BC857B; BC857C			-	-45	V
	BC858B			-	-30	V
V _{EBO}	emitter-base voltage	open collector		-	-5	V
Ic	collector current			-	-100	mA
I _{CM}	peak collector current			-	-200	mA
I _{BM}	peak base current			-	-200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	250	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

 $^{[1] \}quad \text{Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, } 35~\mu\text{m copper, tin-plated and standard footprint.}$

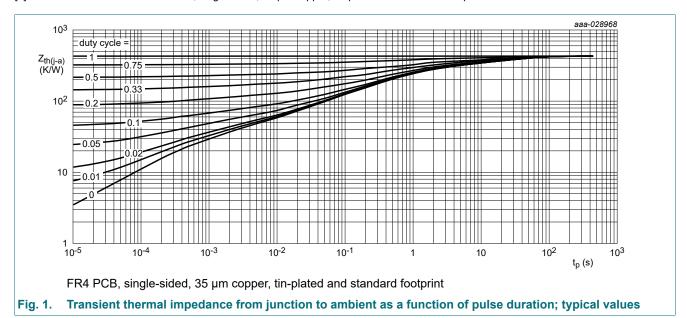
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9. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	500	K/W

[1] Device mounted on an FR4 PCB; single-sided, 35 µm copper; tin-plated and standard footprint.



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10. Characteristics

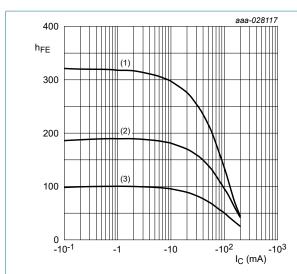
Table 8. Characteristics

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{(BR)CBO}	collector-base breakdown voltage						
BC856; BC856A; BC856B BC857; BC857A; BC857B; BC857C				-80	-	-	V
		I _C = -100 μA; I _E = 0 A		-50	-	-	V
	BC858B			-30	-	-	V
V _{(BR)CEO}	collector-emitter breakdo	own voltage					
	BC856; BC856A; BC856B			-65	-	-	V
	BC857; BC857A; BC857B; BC857C	$I_C = -2 \text{ mA}; I_B = 0 \text{ A}$		-45	-	-	V
BC858B			-30	-	-	V	
V _{(BR)EBO}	emitter-base breakdown voltage	I _C = 0 A; I _E = -100 μA		-5	-	-	V
I _{CBO} collector-base		V _{CB} = -30 V; I _E = 0 A		-	-1	-15	nA
	cut-off current	V _{CB} = -30 V; I _E = 0 A; T _j = 150 °C		-	-	-4	μA
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_C = 0 \text{ A}$		-	-	-100	nA
h _{FE}	DC current gain						
	BC856			125	-	475	
	BC857			125	-	800	
	BC856A; BC857A	$V_{CE} = -5 \text{ V}; I_{C} = -2 \text{ mA}$		125	-	250	
	BC856B; BC857B; BC858B	VGE 0 V, 10 2 1111V		220	-	475	
	BC857C			420	-	800	
V _{CEsat}	collector-emitter	I _C = -10 mA; I _B = -0.5 mA		-	-75	-300	mV
	saturation voltage	I _C = -100 mA; I _B = -5 mA	[1]	-	-250	-650	mV
V _{BEsat}	base-emitter saturation	I _C = -10 mA; I _B = -0.5 mA	[1]	-	-700	-	mV
	voltage	$I_C = -100 \text{ mA}; I_B = -5 \text{ mA}$	[1]	-	-850	-	mV
V_{BE}	base-emitter voltage	$V_{CE} = -5 \text{ V}; I_{C} = -2 \text{ mA}$		-600	-650	-750	mV
		$V_{CE} = -5 \text{ V}; I_{C} = -10 \text{ mA}$		-	-	-820	mV
C _c	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = I_e = 0 \text{ A}; f = 1 \text{ MHz}$		-	4.5	-	pF
f _T	transition frequency	$V_{CE} = -5 \text{ V}; I_{C} = -10 \text{ mA}; f = 100 \text{ MHz}$		100	-	-	MHz
NF	noise figure	I_C = -200 μA; V_{CE} = -5 V; R_S = 2 kΩ; f = 1 kHz; B = 200Hz		-	2	10	dB

^[1] pulsed; $t_p \le 300 \ \mu s; \ \delta \le 0.02$

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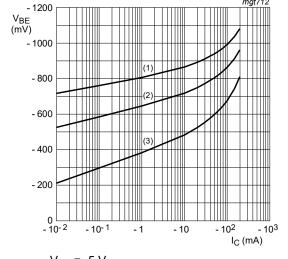


$$V_{CE} = -5 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$



$$V_{CE} = -5 V$$

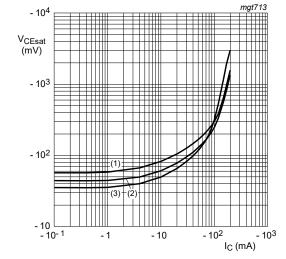
(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

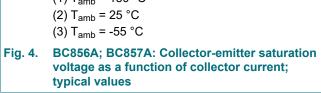
Fig. 2. BC856A; BC857A: DC current gain as a function of collector current; typical values

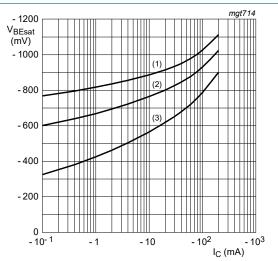




$$I_C/I_B = 20$$

$$(1) T_{amb} = 150 °C$$





$$I_{\rm C}/I_{\rm B} = 20$$

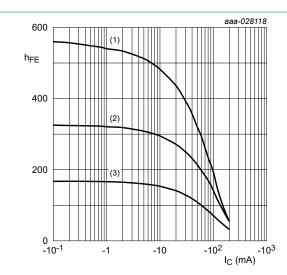
(1)
$$T_{amb} = -55$$
 °C

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 5. BC856A; BC857A: Base-emitter saturation voltage as a function of collector current; typical values

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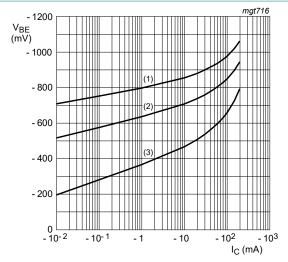
$$V_{CE} = -5 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55$$
 °C

Fig. 6. BC856B; BC857B; BC858B: DC current gain as a function of collector current; typical values



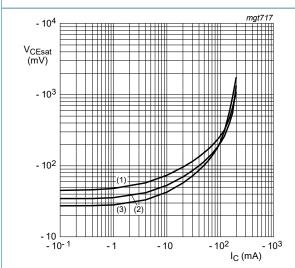
$$V_{CE} = -5 V$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 7. BC856B; BC857B; BC858B: Base-emitter voltage as a function of collector current; typical values



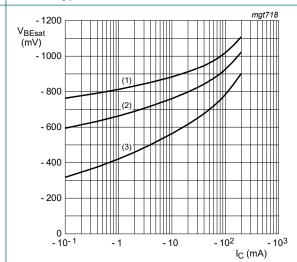
$$I_{\rm C}/I_{\rm B} = 20$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 8. BC856B; BC857B; BC858B: Collector-emitter saturation voltage as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 20$$

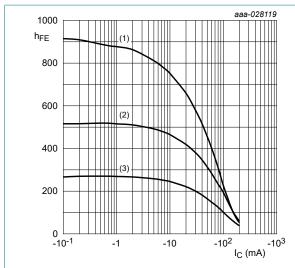
(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 9. BC856B; BC857B; BC858B: Base-emitter saturation voltage as a function of collector current; typical values

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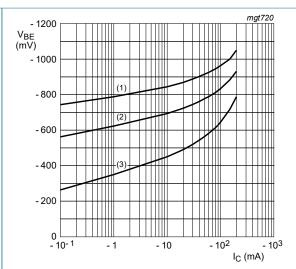
$$V_{CE} = -5 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 10. BC857C: DC current gain as a function of collector current; typical values



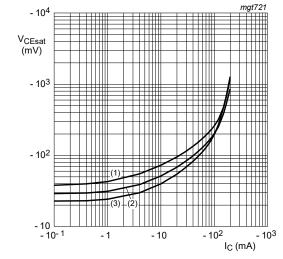
$$V_{CE} = -5 V$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 11. BC857C: Base-emitter voltage as a function of collector current; typical values



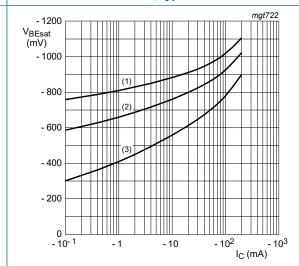
$$I_C/I_B = 20$$

$$(1) T_{amb} = 150 °C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 20$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

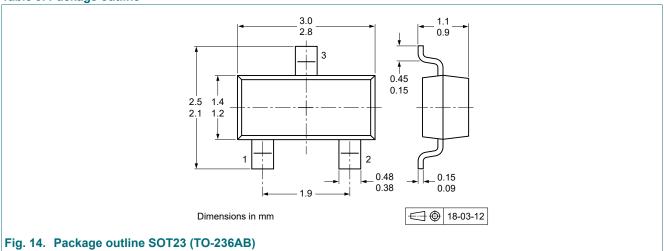
Fig. 12. BC857C: Collector-emitter saturation voltage as | Fig. 13. BC857C: Base-emitter saturation voltage as a function of collector current; typical values

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11. Package outline

Table 9. Package outline



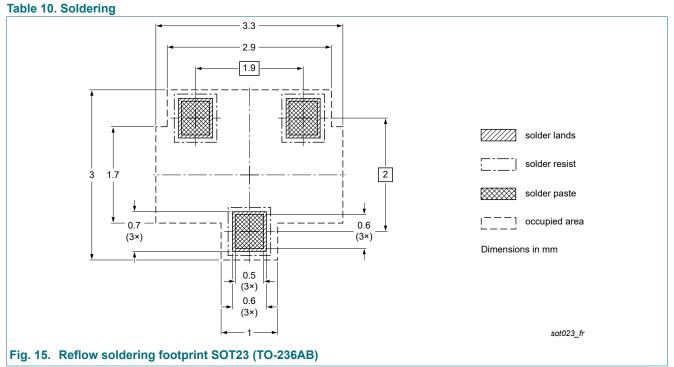
Product data sheet

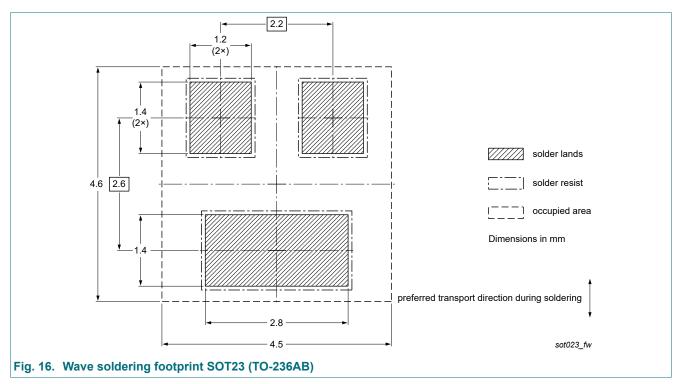
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12. Soldering







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13. Revision history

Table 11. Revision history

Tubic 11. Revision mistory					
Document ID	Release date	Data sheet status	Change notice	Supersedes	
BC856_BC857_BC858 v.9	20220701	Product data sheet	-	BC856_BC857_BC858 v.8	
Modifications:	 Product(s) changed to non-automotive qualification. Please refer to nexperia.com for automotive (-Q) product alternative(s). 				
BC856_BC857_BC858 v.8	20210221	Product data sheet	-	BC856_BC857_BC858 v.7	
BC856_BC857_BC858 v.7	20180416	Product data sheet	-	BC856_BC857_BC858 v.6	
BC856_BC857_BC858 v.6	20040106	Product data sheet	-	BC856_BC857_BC858 v.5	

14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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Nexperia

BC856; BC857; BC858

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Date of release: 1 July 2022

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